



## GaAs InGaP HBT MMIC POWER AMPLIFIER, 1.6 - 2.2 GHz

### Typical Applications

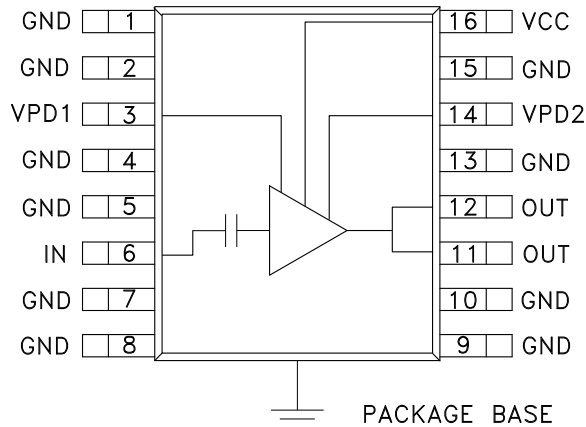
This amplifier is ideal for use as a power/driver amplifier for 1.6 - 2.2 GHz applications:

- Cellular / PCS / 3G
- Portable & Infrastructure
- Wireless Local Loop

### Features

- Gain: 23 dB
- Saturated Power: +29.5 dBm
- 42% PAE
- Supply Voltage: +2.75V to +5V
- Power Down Capability
- Low External Part Count
- Included in the HMC-DK002 Designer's Kit

### Functional Diagram



### General Description

The HMC413QS16G & HMC413QS16GE are high efficiency GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC Power amplifiers which operate between 1.6 and 2.2 GHz. The amplifier is packaged in a low cost, surface mount 16 lead package with an exposed base for improved RF and thermal performance. With a minimum of external components, the amplifier provides 23 dB of gain, +29.5 dBm of saturated power at 42% PAE from a +5V supply voltage. The amplifier can also operate with a 3.6V supply. Vpd can be used for full power down or RF output power/current control.

### Electrical Specifications, $T_A = +25^\circ\text{C}$ , As a Function of $V_s$ , $V_{pd} = 3.6\text{V}$

| Parameter                                  | Frequency                          | $V_s = 3.6\text{V}$ |           |       | $V_s = 5\text{V}$ |           |       | Units |
|--|------------------------------------|---------------------|-----------|-------|-------------------|-----------|-------|-------|
|  |                                    | Min.                | Typ.      | Max.  | Min.              | Typ.      | Max.  |       |
| Gain                                       | 1.6 - 1.7 GHz                      | 18                  | 21        |       | 19                | 22        |       | dB    |
|  | 1.7 - 2.0 GHz                      | 19                  | 22        |       | 20                | 23        |       | dB    |
|  | 2.0 - 2.1 GHz                      | 18                  | 21        |       | 19                | 22        |       | dB    |
|  | 2.1 - 2.2 GHz                      | 17                  | 20        |       | 18                | 21        |       | dB    |
| Gain Variation Over Temperature            | 1.6 - 2.2 GHz                      |                     | 0.025     | 0.035 |                   | 0.025     | 0.035 | dB/°C |
| Input Return Loss                          | 1.6 - 2.2 GHz                      |                     | 10        |       |                   | 10        |       | dB    |
| Output Return Loss                         | 1.6 - 2.2 GHz                      |                     | 8         |       |                   | 9         |       | dB    |
| Output Power for 1 dB Compression (P1dB)   | 1.6 - 1.7 GHz                      | 20                  | 23        |       | 23                | 26        |       | dBm   |
|  | 1.7 - 2.2 GHz                      | 21                  | 24        |       | 24                | 27        |       | dBm   |
| Saturated Output Power (P <sub>sat</sub> ) | 1.6 - 1.7 GHz                      |                     | 25.5      |       |                   | 28.5      |       | dBm   |
|  | 1.7 - 2.2 GHz                      |                     | 26.5      |       |                   | 29.5      |       | dBm   |
| Output Third Order Intercept (IP3)         | 1.6 - 1.7 GHz                      | 32                  | 35        |       | 36                | 39        |       | dBm   |
|  | 1.7 - 2.0 GHz                      | 33                  | 36        |       | 37                | 40        |       | dBm   |
|  | 2.0 - 2.2 GHz                      | 32                  | 35        |       | 36                | 39        |       | dBm   |
| Noise Figure                               | 1.6 - 2.2 GHz                      |                     | 5.5       |       |                   | 5.5       |       | dB    |
| Supply Current (I <sub>cq</sub> )          | V <sub>pd</sub> = 0V/3.6V          |                     | 0.002/220 |       |                   | 0.002/270 |       | mA    |
| Control Current (I <sub>pd</sub> )         | V <sub>pd</sub> = 3.6V             |                     | 7         |       |                   | 7         |       | mA    |
| Switching Speed                            | t <sub>ON</sub> , t <sub>OFF</sub> |                     | 80        |       |                   | 80        |       | ns    |

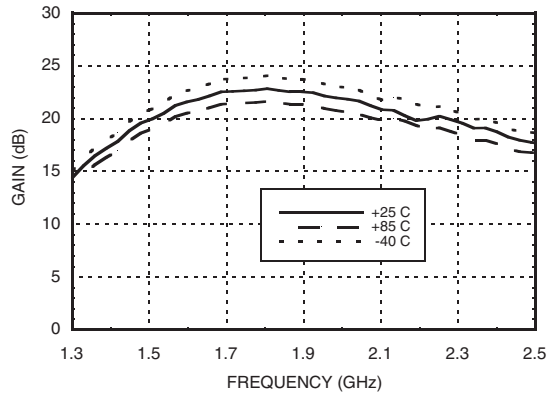
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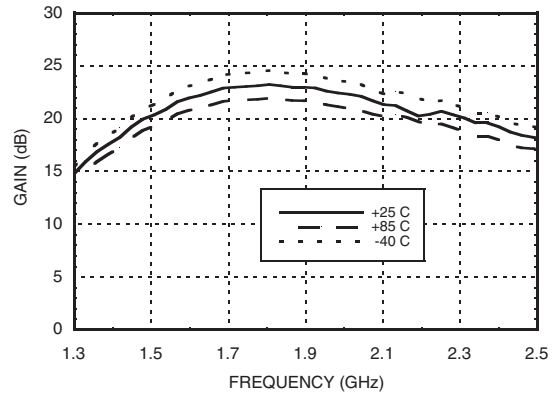


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POWER AMPLIFIER, 1.6 - 2.2 GHz**

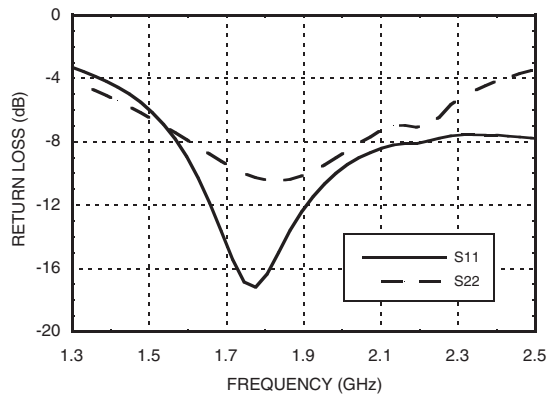
**Gain vs. Temperature, Vs= 3.6V**



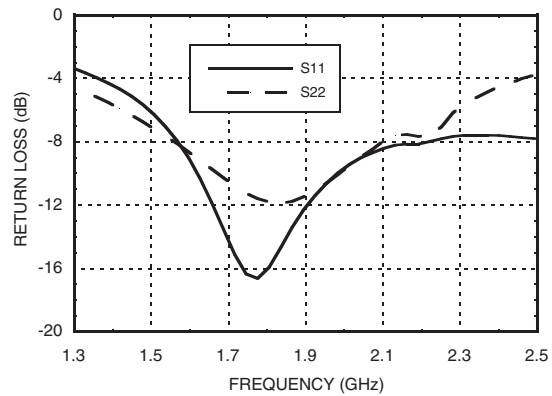
**Gain vs. Temperature, Vs= 5V**



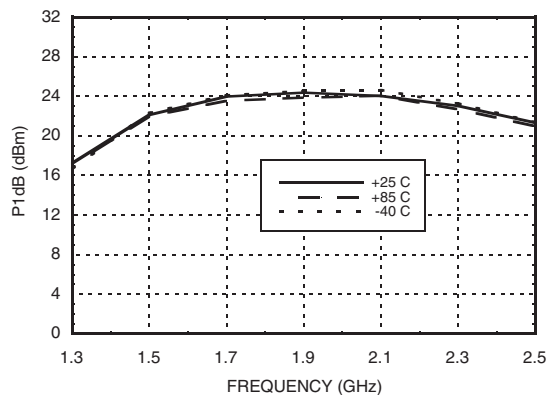
**Return Loss, Vs= 3.6V**



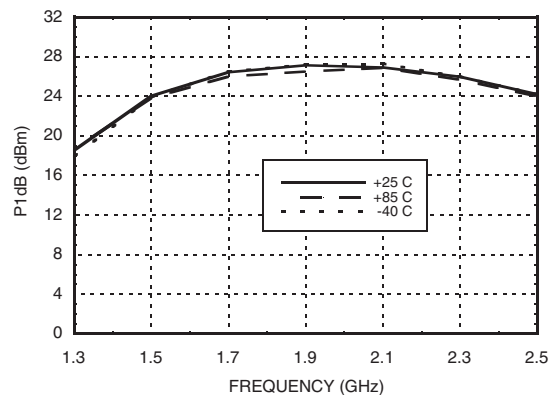
**Return Loss, Vs= 5V**



**P1dB vs. Temperature, Vs= 3.6V**



**P1dB vs. Temperature, Vs= 5V**



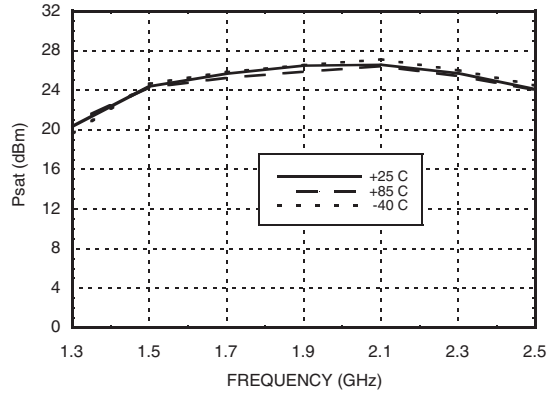
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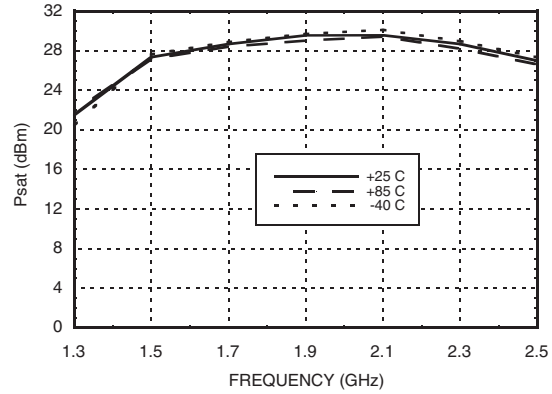


**GaAs InGaP HBT MMIC  
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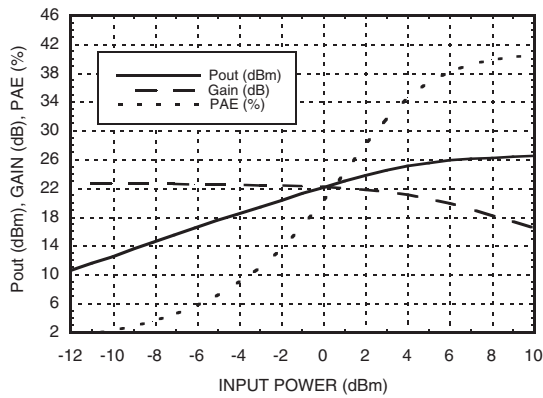
**Psat vs. Temperature, Vs= 3.6V**



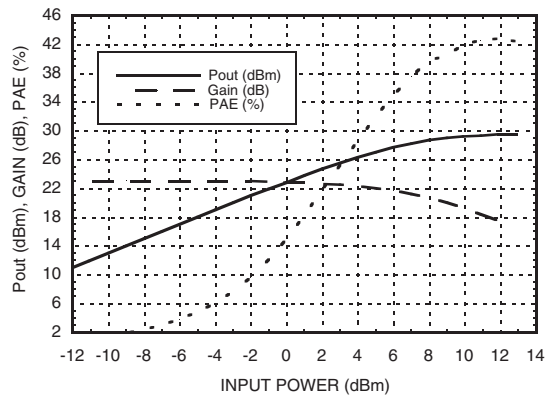
**Psat vs. Temperature, Vs= 5V**



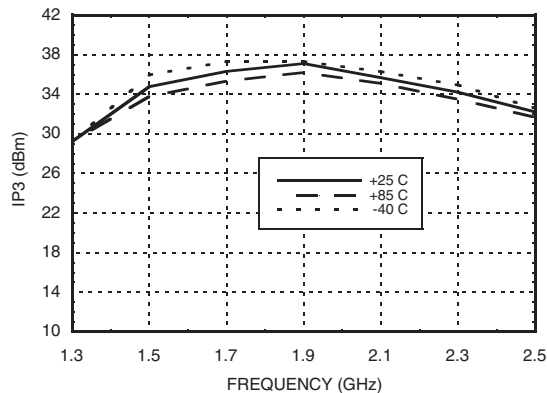
**Power Compression@ 1.9 GHz, Vs= 3.6V**



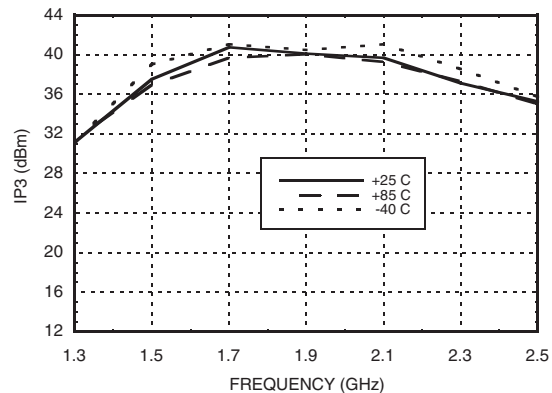
**Power Compression@ 1.9 GHz, Vs= 5V**



**Output IP3 vs. Temperature, Vs= 3.6V**



**Output IP3 vs. Temperature, Vs= 5V**



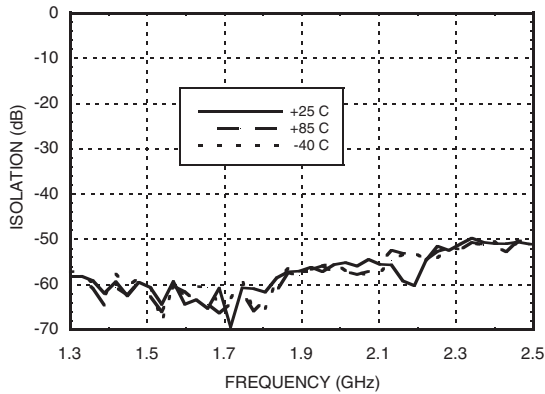
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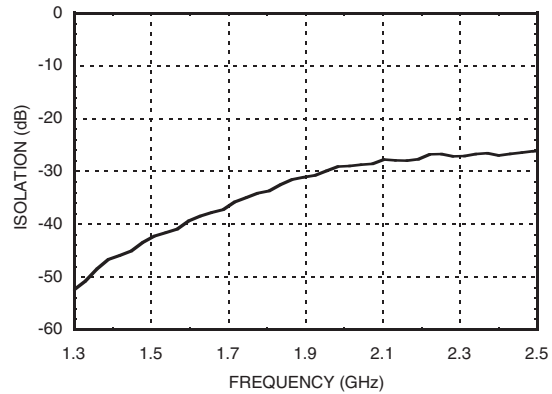


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POWER AMPLIFIER, 1.6 - 2.2 GHz**

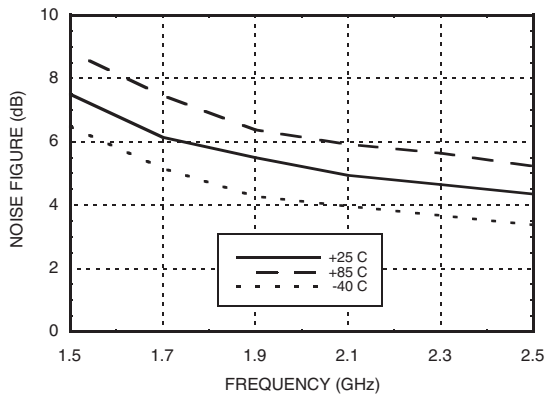
**Reverse Isolation vs. Temperature, Vs= 3.6V**



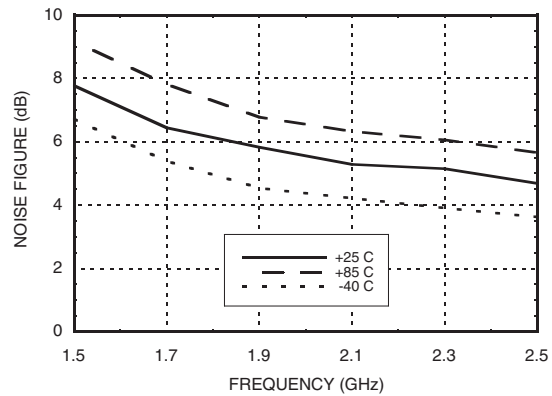
**Power Down Isolation, Vs= 3.6V**



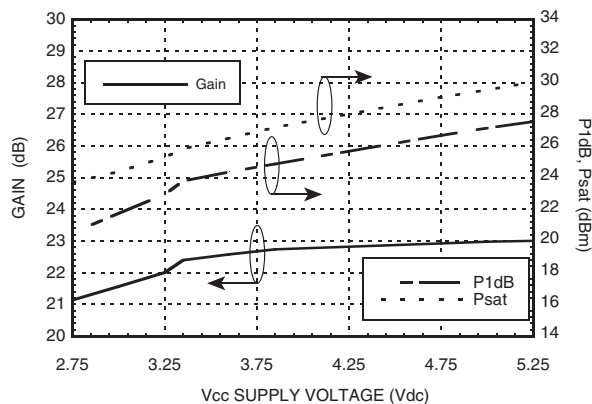
**Noise Figure vs. Temperature, Vs= 3.6V**



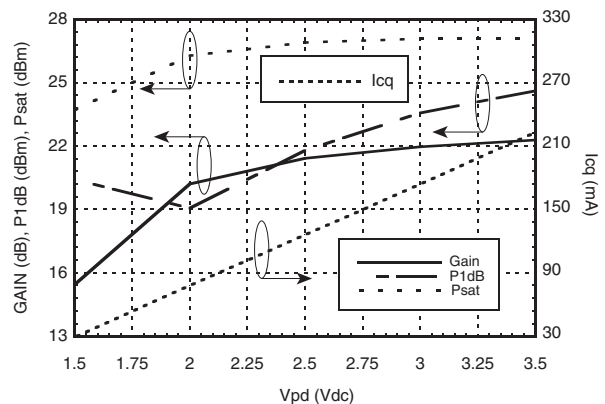
**Noise Figure vs. Temperature, Vs= 5V**



**Gain & Power vs. Supply Voltage @ 1.9 GHz**



**Gain, Power & Quiescent Supply Current vs. Vpd @ 1.9 GHz, Vcc = +3.6V**



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## GaAs InGaP HBT MMIC POWER AMPLIFIER, 1.6 - 2.2 GHz

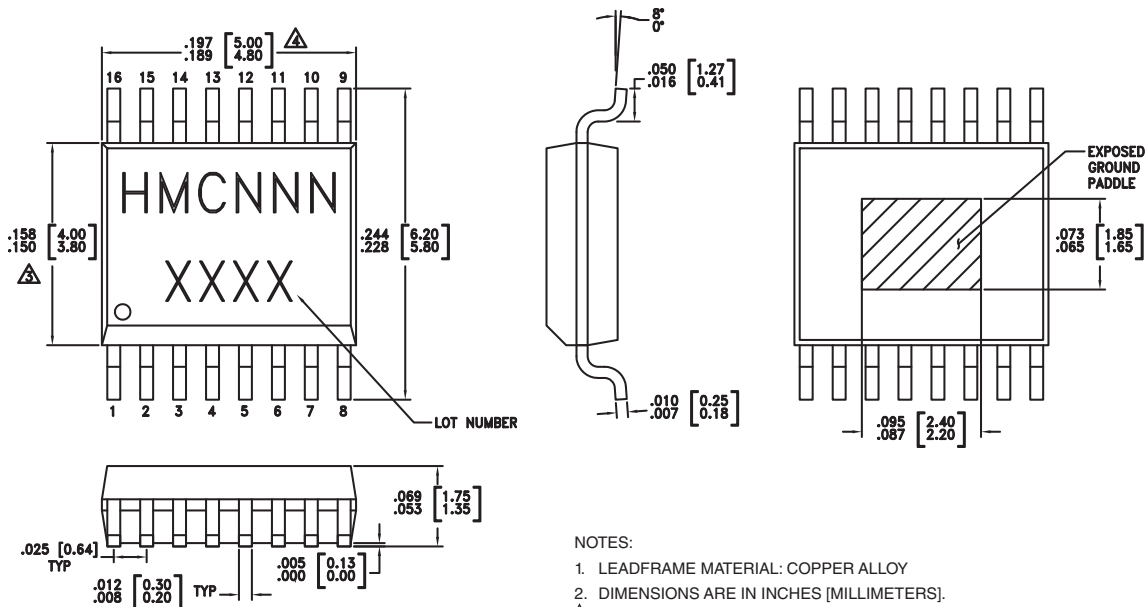
### Absolute Maximum Ratings

|   |                |
|---|----------------|
| Collector Bias Voltage (Vcc)  | +5.5 Vdc       |
| Control Voltage (Vpd1, Vpd2)  | +4.0 Vdc       |
| RF Input Power (RFIN)(Vs = +5Vdc, Vpd = +3.6 Vdc)                         | +15 dBm        |
| Junction Temperature  | 150 °C         |
| Continuous P <sub>diss</sub> (T = 85 °C)<br>(derate 24 mW/°C above 85 °C) | 1.56 W         |
| Thermal Resistance<br>(junction to ground paddle)                         | 42 °C/W        |
| Storage Temperature   | -65 to +150 °C |
| Operating Temperature   | -40 to +85 °C  |



ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS

### Outline Drawing



NOTES:

- LEADFRAME MATERIAL: COPPER ALLOY
- DIMENSIONS ARE IN INCHES (MILLIMETERS).
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

### Package Information

| Part Number  | Package Body Material                              | Lead Finish   | MSL Rating          | Package Marking <sup>[3]</sup> |
|--------------|--|---------------|---------------------|--------------------------------|
| HMC413QS16G  | Low Stress Injection Molded Plastic                | Sn/Pb Solder  | MSL1 <sup>[1]</sup> | HMC413<br>XXXX                 |
| HMC413QS16GE | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 <sup>[2]</sup> | HMC413<br>XXXX                 |


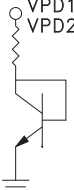
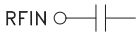
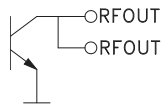
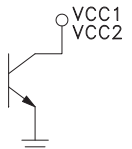
[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX



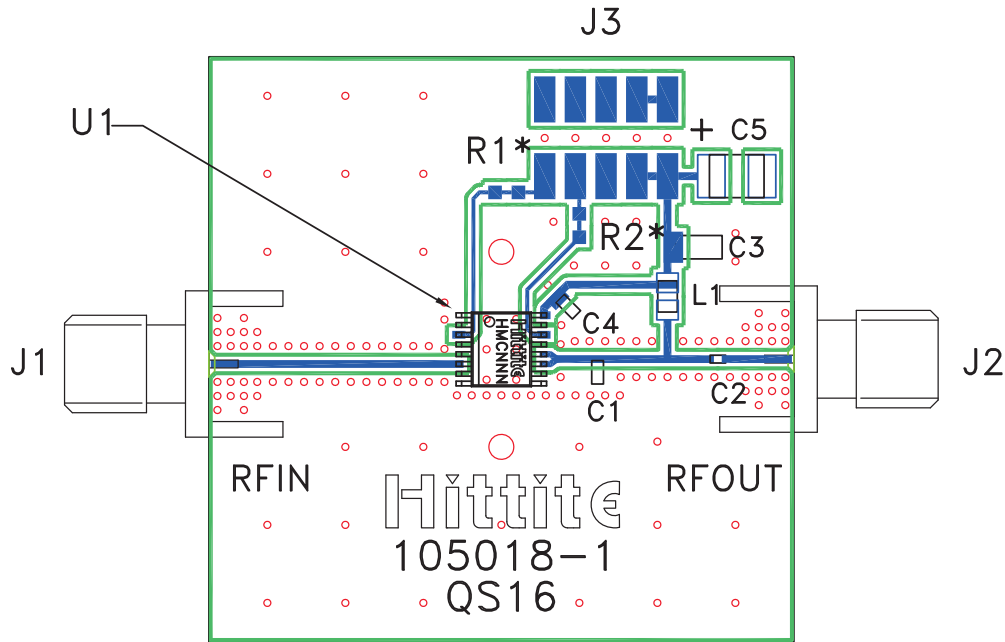
### Pin Descriptions

| Pin Number                      | Function   | Description  | Interface Schematic   |
|---------------------------------|------------|--|---|
| 1, 2, 4, 5, 7, 8, 9, 10, 13, 15 | GND        | Ground: Backside of package has exposed metal ground slug that must be connected to ground thru a short path. Vias under the device are required.  |    |
| 3, 14                           | Vpd1, Vpd2 | Power Control Pin. For maximum power, this pin should be connected to 3.6V. For 5V operation, a dropping resistor is required. A higher voltage is not recommended. For lower idle current, this voltage can be reduced. |    |
| 6                               | RFIN       | This pin is AC coupled and matched to 50 Ohms from 1.6 to 2.2 GHz.   |    |
| 11, 12                          | RFOUT      | RF output and bias for the output stage.   |    |
| 16                              | Vcc        | Power supply voltage for the first amplifier stage. An external bypass capacitor of 330 pF is required as shown in the application schematic.  |  |



**GaAs InGaP HBT MMIC  
POWER AMPLIFIER, 1.6 - 2.2 GHz**

**Evaluation PCB**



\* For 5V operation on Vctl line, select R1, R2 such that 3.6V is presented on Pins 3 and 14.

**List of Materials for Evaluation PCB 105000 [1]**

| Item    | Description                          |
|---------|--------------------------------------|
| J1 - J2 | PCB Mount SMA RF Connector           |
| J3      | 2 mm DC Header                       |
| C1      | 2.2 pF Capacitor, 0603 Pkg.          |
| C2      | 10 pF Capacitor, 0402 Pkg.           |
| C3 - C4 | 330 pF Capacitor, 0603 Pkg.          |
| C5      | 2.2 μF Capacitor, Tantalum           |
| L1      | 16 nH Inductor 0603 Pkg.             |
| U1      | HMC413QS16G / HMC413QS16GE Amplifier |
| PCB [2] | 105018 Eval Board                    |

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

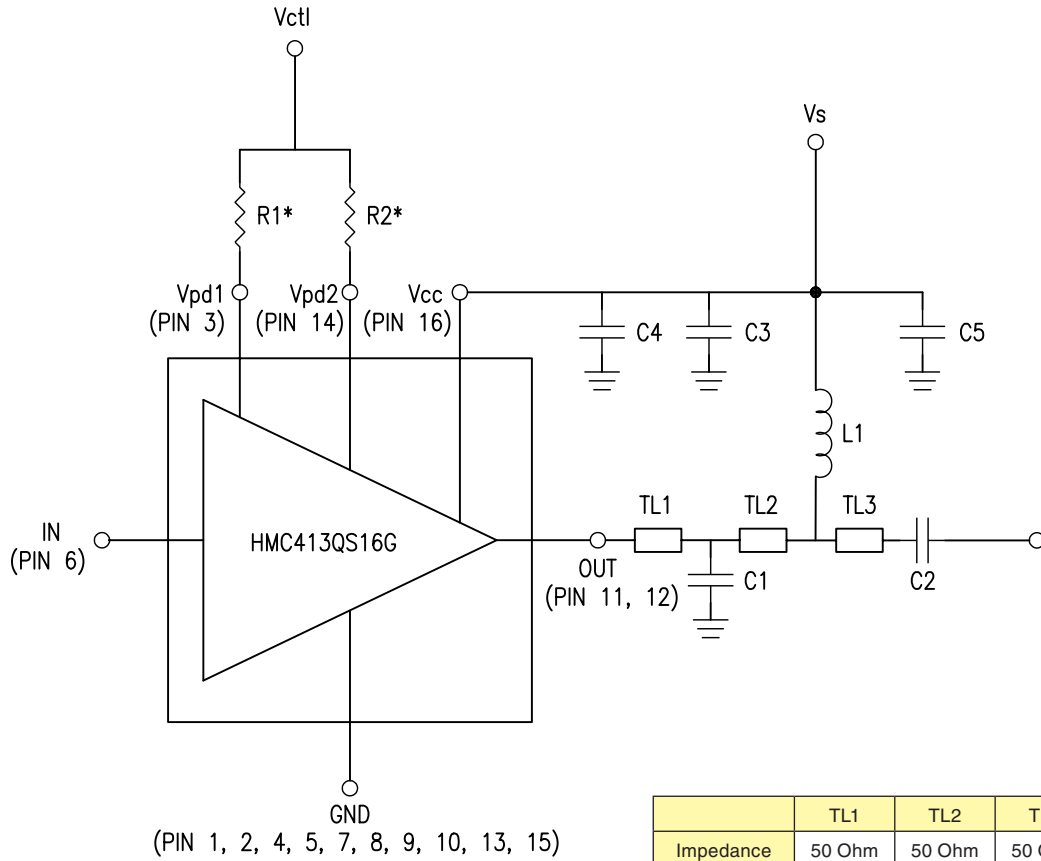
[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350



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**Application Circuit**



|           | TL1    | TL2    | TL3    |
|-----------|--------|--------|--------|
| Impedance | 50 Ohm | 50 Ohm | 50 Ohm |
| Length    | 0.1"   | 0.15"  | 0.1"   |

\* For 5V operation on Vctl line, select R1, R2 such that 3.6V is presented on Pins 3 and 14.



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